

# SMD Schottky Barrier Diode

**COACHIP**  
SMD Diodes Specialist

## CDBF0130 (Lead-free Device)

$I_o = 100 \text{ mA}$

$V_R = 30 \text{ Volts}$

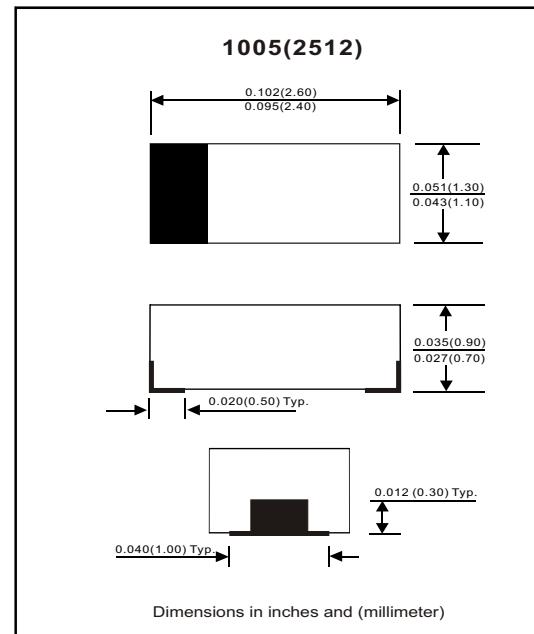


### Features

- Designed for mounting on small surface.
- Extremely thin package.
- Low stored charge.
- Majority carrier conduction.

### Mechanical data

- Case: 1005(2512) standard package, molded plastic.
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band.
- Mounting position: Any
- Weight: 0.006 gram(approx.).



### Maximum Rating (at $TA=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Repetitive peak reverse voltage		$V_{RRM}$			35	V
Reverse voltage		$V_R$			30	V
Average forward current		$I_o$			100	mA
Forward current,surge peak	8.3 ms single half sine-wave superimposed on rate load(JEDEC method)	$I_{FSM}$		1000		mA
Power Dissipation		$P_D$			250	mW
Sunction temperature		$T_{STG}$	-40		+125	°C
Junction temperature		$T_j$			+125	°C

### Electrical Characteristics (at $TA=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 100 \text{ mA DC}$	$V_F$			0.44	V
Reverse current	$V_R = 30V$	$I_R$			30	uA
Capacitance between terminals	$F = 1 \text{ MHZ}$ and 10 VDC reverse voltage	$C_T$		9		pF

## RATING AND CHARACTERISTIC CURVES (CDBF0130)

Fig. 1 - Forward characteristics

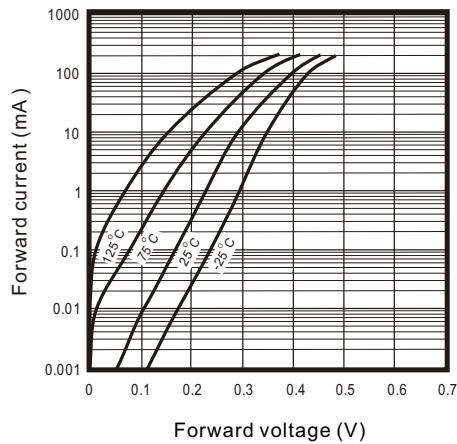


Fig. 2 - Reverse characteristics

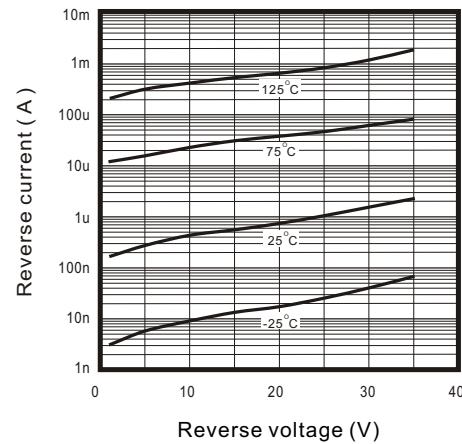


Fig.3 - Capacitance between terminals characteristics

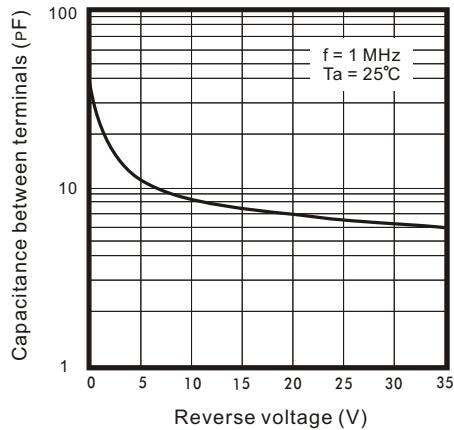


Fig.4 - Current derating curve

